

PNP RF Transistor MMBTH81

This device is designed for general RF amplifier and mixer applications to 250 MHz with collector currents in the 1.0 mA to 30 mA range. Sourced from Process 75.

Features

- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements;
 AEC-Q101 Qualified and PPAP Capable

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Units
Collector - Emitter Voltage	V _{CEO}	20	V
Collector - Base Voltage	V _{CBO}	20	V
Emitter - Base Voltage	V _{EBO}	3.0	V
Collector Current - Continuous	I _C	50	mA
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

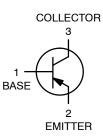
Characteristic	Symbol	Max	Unit
Total Device Dissipation Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Device mounted on FR-4 PCB $1.6 \times 1.6 \times 0.06$ in.
- 2. These ratings are based on a maximum junction temperature of $150\,^{\circ}$ C.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

1

4. All voltages (V) and currents (A) are negative polarity for PNP transistors.





SOT-23 CASE 318-08 STYLE 6

MARKING DIAGRAM



3D = Specific Device Code

M = Date Code*

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

MMBTH81

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Max	Units	
OFF CHARA	OFF CHARACTERISTICS					
V _{(BR)CEO}	Collector - Emitter Breakdown Voltage (Note 5)	I _C = 1.0 mA, I _B = 0	20		V	
V _{(BR)CBO}	Collector - Base Breakdown Voltage	$I_C = 10 \mu A, I_E = 0$	20		V	
V _{(BR)EBO}	Emitter - Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	3.0		V	
I _{CBO}	Collector Cutoff Current	V _{CB} = 10 V, I _E = 0		100	nA	
I _{EBO}	Emitter Cutoff Current	V _{EB} = 2.0 V, I _C = 0		100	nA	
ON CHARAC	ON CHARACTERISTICS					
h _{FE}	DC Current Gain	$I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$	60			
V _{CE(sat)}	Collector - Emitter Saturation Voltage	$I_C = 5.0 \text{ mA}, I_B = 0.5 \text{ mA}$		0.5	V	
V _{BE(on)}	Base - Emitter On Voltage	I _C = 5.0 mA, V _{CE} = 10 V		0.9	V	
SMALL SIGNAL CHARACTERISTICS						
f _T	Current Gain - Bandwidth Product	$I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}, f = 100 \text{ MHz}$	600		MHz	
C _{cb}	Collector-Base Capacitance	V _{CB} = 10 V, I _E = 0, f = 1.0 MHz		0.85	pF	
C _{ce}	Collector Emitter Capacitance	V _{CB} = 10 V, I _B = 0, f = 1.0 MHz		0.65	pF	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

SPICE MODEL

PNP(Is=10f Xti=3 Eg=1.11 Vaf=100 Bf=133.8 Ise=1.678p Ne=2.159 Ikf=.1658 Nk=.901 Xtb=1.5 Var=100 Br=1 Isc=9.519n Nc=3.88 Ikr=5.813 Rc=7.838 Cjc=2.81p Mjc=.1615 Vjc=.8282 Fc=.5 Cje=2.695p Mje=.3214 Vje=.7026 Tr=11.32n Tf=97.83p Itf=69.29 Xtf=599u Vtf=10)

ORDERING INFORMATION

Device	Specific Marking Code	Package	Shipping [†]
NSVMMBTH81LT1G*	3D	SOT-23 (Pb-Free)	3,000 / Tape & Reel
NSVMMBTH81LT3G*	3D	SOT-23 (Pb-Free)	10,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

MMBTH81

TYPICAL CHARACTERISTICS

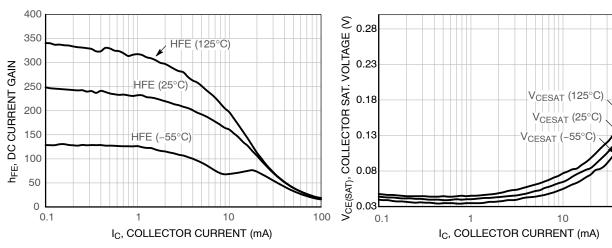
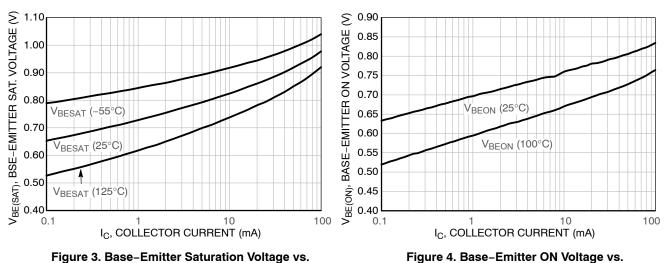


Figure 1. DC Current Gain vs. Collector Current

Figure 2. Collector Saturation Voltage vs.
Collector Current

100



I_{CES} (6 V)

I_{CES} (3 V

150

Figure 3. Base-Emitter Saturation Voltage vs. Collector Current

2.00 1.80 1.60 CAPACITANCE (pF) 1.40 C_{ibo} 1.20 1.00 C_{obo} 0.80 0.60 2 5 6 10 0 4

Collector Current

Figure 5. Collector Reverse Current vs.

Ambient Temperature

TA, AMBIENT TEMPERATURE (°C)

100

75

I_{CES}, COLLECTOR REVERSE CURRENT (nA)

0.60

0.50

0.40

0.30

0.20

0.10

0.00

Figure 6. Input /Output Capacitance vs. Reverse Bias Voltage

REVERSE BIAS VOLTAGE (V)

MILLIMETERS

MIN

0.89

0.01

0.37

0.08

2.80

1.20

1.78

0.30

0.35

2.10

O°

NOM

1.00

0.06

0.44

0.14

2.90

1.30

1.90

0.43

0.54

2.40





SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

DATE 14 AUG 2024

MAX

1.11

0.10

0.50

0.20

3.04

1.40

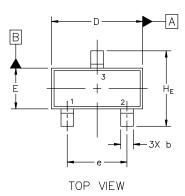
2.04

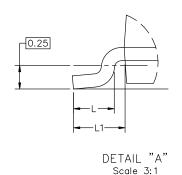
0.55

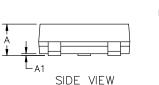
0.69

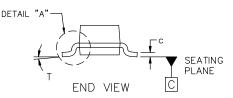
2.64

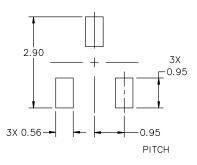
10°













DIM

Α

Α1

b

С

D

Ε

е L

L1

HE

Τ

- DIMENSIONING AND TOLERANCING 1. PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS:
- MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package



* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

SOT-23 (TO-236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	1	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE		PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE		2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE		3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20: PIN 1. CATHODE 2. ANODE 3. GATE
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	N PIN 1. CATHODE	
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODI	
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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